NSN 5961-01-356-8594

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View Online at https://aerobasegroup.com/nsn/5961-01-356-8594 **Inclosure Material:** Ceramic **Overall Length:** 0.071 inches **Overall Diameter:** Between 0.092 inches and 0.108 inches **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 25.0 collector to base voltage/static/emitter open and 12.0 collector to emitter voltage/static/base open and 3.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 70.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0